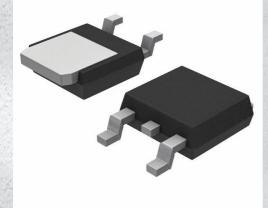


# NJD35N04T4G Datasheet

www.digi-electronics.com

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DiGi Electronics Part Number	NJD35N04T4G-DG
Manufacturer	onsemi
Manufacturer Product Number	NJD35N04T4G
Description	TRANS NPN DARL 350V 4A DPAK
Detailed Description	Bipolar (BJT) Transistor NPN - Darlington 350 V 4 A 90MHz 45 W Surface Mount DPAK

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# Purchase and inquiry

Manufacturer Product Number:	Manufacturer:		
NJD35N04T4G	onsemi		
Series:	Product Status:		
	Active		
Transistor Type:	Current - Collector (Ic) (Max):		
NPN - Darlington	4 A		
Voltage - Collector Emitter Breakdown (Max):	Vce Saturation (Max) @ lb, lc:		
350 V	1.5V @ 20mA, 2A		
Current - Collector Cutoff (Max):	DC Current Gain (hFE) (Min) @ lc, Vce:		
50µA	2000 @ 2A, 2V		
Power - Max:	Frequency - Transition:		
45 W	90MHz		
Operating Temperature:	Mounting Type:		
-65°C ~ 150°C (TJ)	Surface Mount		
Package / Case:	Supplier Device Package:		
TO-252-3, DPAK (2 Leads + Tab), SC-63	DPAK		
Base Product Number:			
NJD35			

# **Environmental & Export classification**

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	
8541.29.0075	

# NJD35N04G, NJVNJD35N04G, NJVNJD35N04T4G

# NPN Darlington Power Transistor

This high voltage power Darlington has been specifically designed for inductive applications such as Electronic Ignition, Switching Regulators and Motor Control.

## Features

- Exceptional Safe Operating Area
- High V<sub>CE</sub>; High Current Gain
- NJV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These are Pb-Free Devices\*

#### Benefits

- Reliable Performance at Higher Powers
- Designed for Inductive Loads
- Very Low Current Requirements

## Applications

- Internal Combustion Engine Ignition Control
- Switching Regulators
- Motor Controls
- Light Ballast
- Photo Flash

## MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Emitter Sustaining Voltage	V <sub>CEO</sub>	350	Vdc
Collector-Base Breakdown Voltage	V <sub>CBO</sub>	700	Vdc
Collector-Emitter Breakdown Voltage	V <sub>CES</sub>	700	Vdc
Emitter-Base Voltage	V <sub>EBO</sub>	5.0	Vdc
Collector Current Continuous Peak	I <sub>С</sub> I <sub>СМ</sub>	4.0 8.0	Adc
Base Current	Ι <sub>Β</sub>	0.5	Adc
Total Power Dissipation @ T <sub>C</sub> = 25°C Derate above 25°C	P <sub>D</sub>	45 0.36	W W/°C
Operating and Storage Junction Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-65 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.



## **ON Semiconductor®**

http://onsemi.com

## DARLINGTON POWER TRANSISTORS 4 AMPERES 350 VOLTS 45 WATTS



DPAK CASE 369C STYLE 1

#### MARKING DIAGRAM



Y = Year WW = Work Week NJD35N04 = Device Code G = Pb-Free Device

#### ORDERING INFORMATION

Device	Package	Shipping <sup>†</sup>
NJD35N04G	DPAK (Pb-Free)	75 Units / Rail
NJVNJD35N04G	DPAK (Pb-Free)	75 Units / Rail
NJD35N04T4G	DPAK (Pb–Free)	2,500 / Tape & Reel
NJVNJD35N04T4G	DPAK (Pb-Free)	2,500 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

## NJD35N04G, NJVNJD35N04G, NJVNJD35N04T4G

## THERMAL CHARACTERISTICS

Characteristic	Symbol	Value	Unit
Thermal Resistance Junction-to-Case Junction-to-Ambient	${\sf R}_{ heta { m JC}} \ {\sf R}_{ heta { m JA}}$	2.78 71.4	°C/W

## **ELECTRICAL CHARACTERISTICS** ( $T_C = 25^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Min	Тур	Мах	Unit
OFF CHARACTERISTICS		I			1
Collector-Emitter Sustaining Voltage $(I_{C} = 10 \text{ mA}, L = 10 \text{ mH})$	V <sub>CEO(sus)</sub>	350	-	-	V
Collector Cutoff Current (V <sub>CE</sub> = 500 V) (I <sub>B</sub> = 0) (V <sub>CE</sub> = 500 V, T <sub>C</sub> = 125°C)	I <sub>CES</sub>			50 250	μΑ
Collector Cutoff Current (V <sub>CE</sub> = 250 V) (I <sub>B</sub> = 0) (V <sub>CE</sub> = 200 V, T <sub>C</sub> = 125°C)	I <sub>CEO</sub>			50 250	μΑ
Emitter Cutoff Current (V <sub>BE</sub> = 5.0 Vdc)	I <sub>EBO</sub>	-	-	5.0	μΑ
ON CHARACTERISTICS	•	L	•	•	•
Collector–Emitter Saturation Voltage ( $I_C = 2.0 \text{ A}$ , $I_B = 20 \text{ mA}$ ) ( $I_C = 2.0 \text{ A}$ , $I_B = 20 \text{ mA } 125^{\circ}\text{C}$ )	V <sub>CE(sat)</sub>			1.5 1.5	V
Base-Emitter Saturation Voltage ( $I_C = 2.0 \text{ A}$ , $I_B = 20 \text{ mA}$ ) ( $I_C = 2.0 \text{ A}$ , $I_B = 20 \text{ mA } 125^{\circ}\text{C}$ )	V <sub>BE(sat)</sub>			2.0 2.0	V
Base–Emitter On Voltage (I <sub>C</sub> = 2.0 A, V <sub>CE</sub> = 2.0 V) (I <sub>C</sub> = 2.0 A, V <sub>CE</sub> = 2.0 V[]25°C)	V <sub>BE(on)</sub>			2.0 2.0	V
DC Current Gain (I <sub>C</sub> = 2.0 A, V <sub>CE</sub> = 2.0 V) (I <sub>C</sub> = 4.0 A, V <sub>CE</sub> = 2.0 Vdc)	h <sub>FE</sub>	2000 300			_
DYNAMIC CHARACTERISTICS		ł	ł	ł	ł
Current–Gain – Bandwidth Product (I <sub>C</sub> = 2.0 A, V <sub>CE</sub> = 10 V, f = 1.0 MHz)	fT	90	_	_	MHz
Output Capacitance (V <sub>CB</sub> = 10 V, I <sub>E</sub> = 0, f = 0.1 MHz)	C <sub>ob</sub>	_	60	_	pF
SWITCHING CHARACTERISTICS	4	ļ	ļ	ļ	ļ
$V_{CC}$ = 12 V, $V_{clamp}$ = 250 V, L = 4 mH I <sub>C</sub> = 2 A, I <sub>B1</sub> = 20 mA, I <sub>B2</sub> = -20 mA	t <sub>s</sub> t <sub>f</sub>		18 0.8		μSec
			1	1	

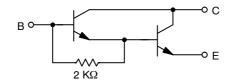
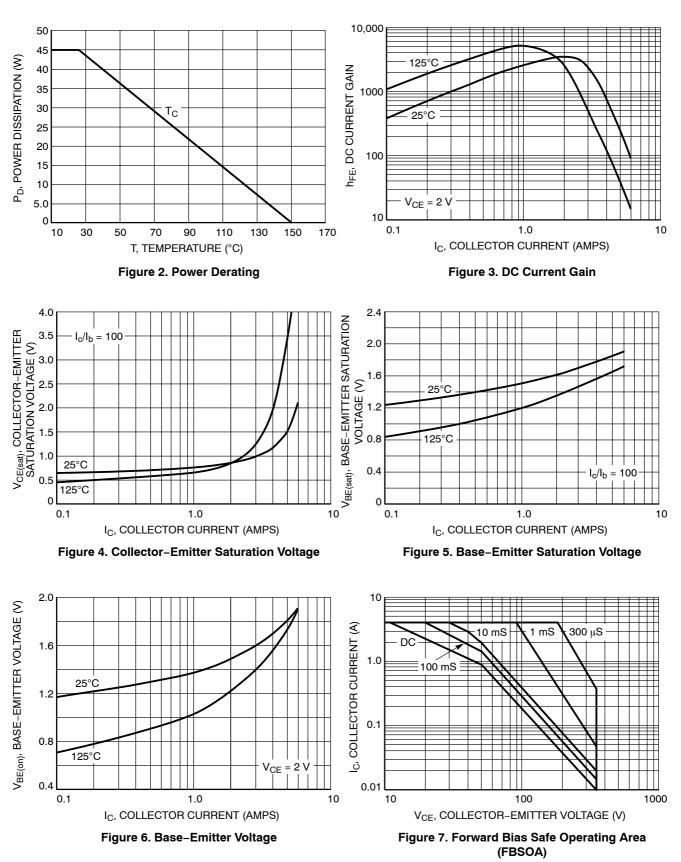


Figure 1. Darlington Circuit Schematic

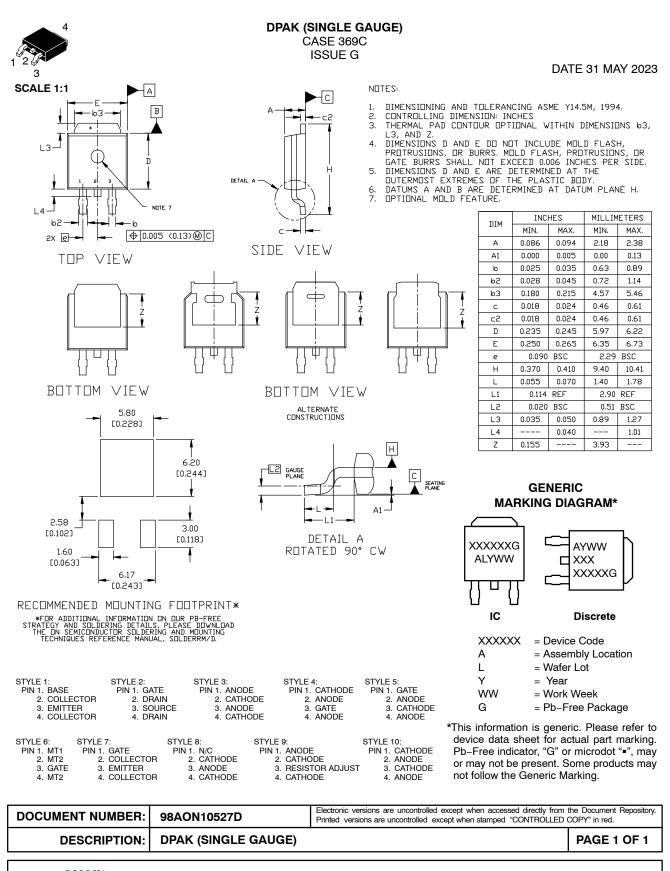
## NJD35N04G, NJVNJD35N04G, NJVNJD35N04T4G



## **TYPICAL CHARACTERISTICS**



PACKAGE DIMENSIONS



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